

ZXT10P20DE6

20V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

- $BV_{CEO} > -20V$
- I_C = -2.5A Continuous Collector Current
- I_{CM} = -6A Peak Pulse Current
- $R_{CE(sat)} = 96m\Omega$ for a low equivalent On-Resistance
- Low Saturation Voltage (-220mV max @ 1A)
- hFE characterized up to -6A for high current gain hold up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

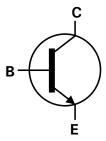
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (approximate)

Applications

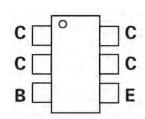
- DC DC Converters
- **Power Management Functions**
- **Power Switches**
- Motor Control







Device Symbol



Pin-Out Top

Ordering Information (Note 4)

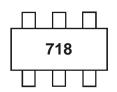
Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT10P20DE6TA	718	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com

Marking Information



718 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-20	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7	V
Base Current	l _Β	-500	mA
Continuous Collector Current	Ic	-2.5	Α
Peak Pulse Collector Current	I _{CM}	-6	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		1.1 8.8	W	
Linear Derating Factor	(Note 6)	P _D	1.7 13.6	mW/°C	
Thermal Desistance Junction to Ambient	(Note 5)	D	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ hetaJA}$	73	°C/VV	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{ heta JL}$	30.01	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

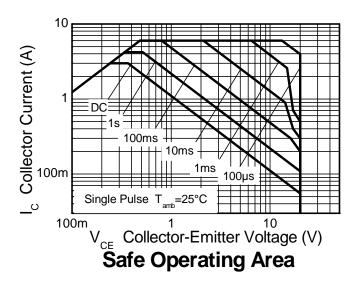
Notes:

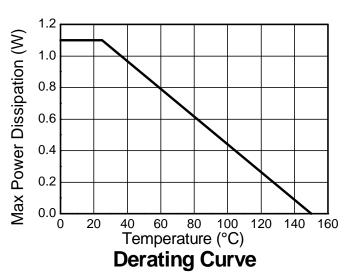
- 5. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- 6. Same as note (5), except the device is measured at $t \le 5$ sec.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

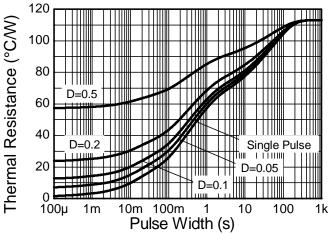
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information







Transient Thermal Impedance



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

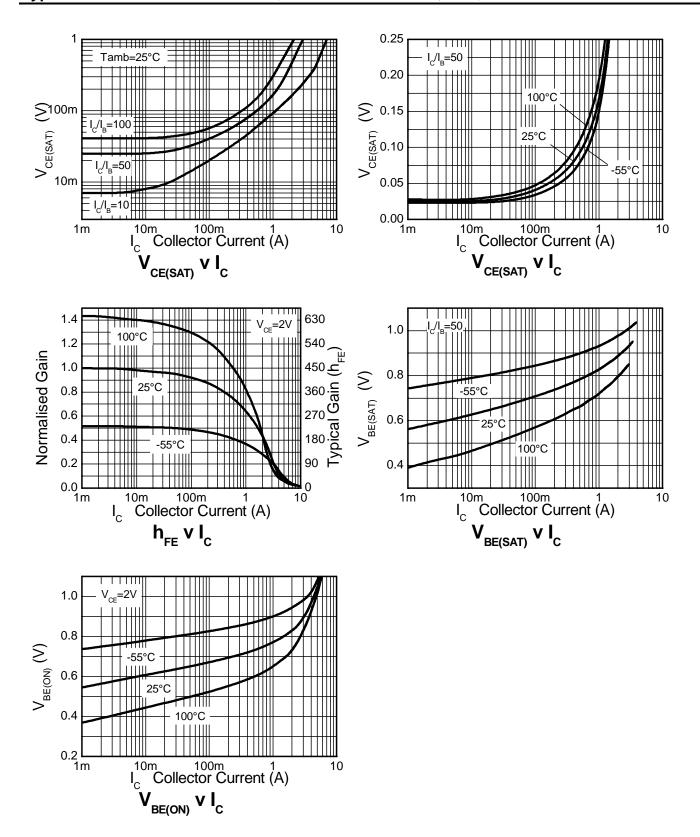
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	-20	-65	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-20	-53		V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.8	_	V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I _{CBO}	_	<1	-100	nA	V _{CB} = -15V
Emitter Cutoff Current	I _{EBO}	_	<1	-100	nA	V _{EB} = -5V
Collector-Emitter Cutoff Current	I _{CES}	_	<1	-100	nA	V _{CES} = -15V
ON CHARACTERISTICS (Note 9)						
		300	475	_	_	$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain	h	300	450		_	$I_C = -0.1A, V_{CE} = -2V$
DC Current Gain	h _{FE}	150	230		_	$I_{C} = -2A$, $V_{CE} = -2V$
		15	30	_	_	$I_C = -6A$, $V_{CE} = -2V$
	V _{CE(sat)}	_	-19	-30	mV	$I_C = -0.1A$, $I_B = -10mA$
Collector Emitter Seturation Voltage		_	-170	-220		$I_C = -1A$, $I_B = -20mA$
Collector-Emitter Saturation Voltage		_	-190	-250		$I_C = -1.5A$, $I_B = -50mA$
		_	-240	-350		I _C = -2.5A, I _B = -150mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	-0.97	-1.05	V	$I_C = -2.5A$, $I_B = -150mA$
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	-0.85	-0.95	V	I _C = -2.5A, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T	150	180	_	MHz	$V_{CE} = -10V$, $I_{C} = -50mA$, $f = 100MHz$
Output Capacitance	Cobo	_	21	30	pF	V _{CB} = -10V, f = 1MHz
Turn-On Time	t _(on)	_	40	_	ns	$V_{CC} = -10V, I_C = -1A$
Turn-Off Time	t _(Off)	_	670	_	ns	$I_{B1} = -I_{B2} = -20 \text{mA}$

Notes: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.





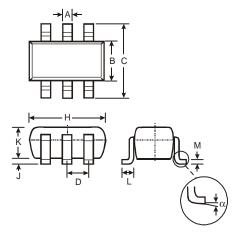
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

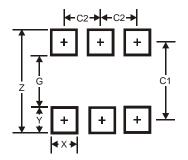
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT26					
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	_	_	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
M	0.10	0.20	0.15			
α	0°	8°	_			
All D	All Dimensions in mm					

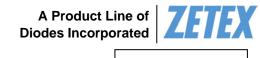
Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95





ZXT10P20DE6

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